

PS2913-1

SINGLE Tr. OUTPUT, HIGH COLLECTOR TO EMITTER VOLTAGE 4-PIN ULTRA SMALL FLAT-LEAD PHOTOCOUPLER

R08DS0113EJ0202 Rev.2.02 Dec 6, 2021

Data Sheet

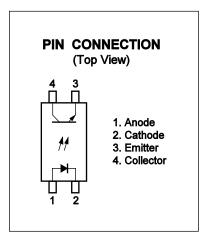
DESCRIPTION

The PS2913-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon phototransistor in one package for high density mounting applications.

An ultra small flat-lead package has been provided which realizes a reduction in mounting area of about 30% compared with the PS28xx series.

FEATURES

- Ultra small flat-lead package (4.6 (L) \times 2.5 (W) \times 2.1 (H) mm)
- High collector to emitter voltage (VCEO = 120 V)
- High isolation voltage (BV = 2 500 Vr.m.s.)
- Ordering number of taping product: PS2913-1-F3: 3 500 pcs/reel
- Safety standards
 - UL approved: UL1577, Single protection
 - BSI approved: BS EN 62368-1, Supplementary insulation
 - VDE approved: DIN EN 60747-5-5 (Option)

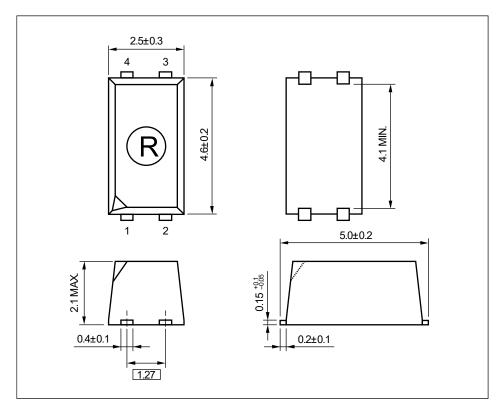


APPLICATIONS

- DC/DC converter
- Modem/PC card

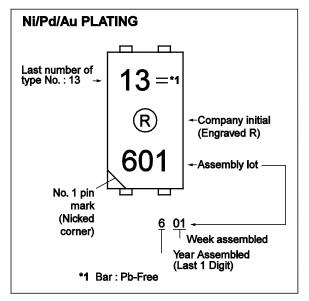


PACKAGE DIMENSIONS (UNIT: mm)



Weight: 0.05g (typ.)

MARKING EXAMPLE



PHOTOCOUPLER CONSTRUCTION

Parameter	MIN.
Air Distance	4 mm
Creepage Distance	4 mm
Isolation Distance	0.4 mm



ORDERING INFORMATION

Part Number	Order Number*1	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number ^{*2}
PS2913-1	PS2913-1-AX	Pb-Free	50 pcs (Tape 50 pcs cut)	Standard products	PS2913-1
PS2913-1-F3	PS2913-1-F3- AX	(Ni/Pd/Au)	Embossed Tape 3 500 pcs/reel	(UL, BSI approved)	
PS2913-1-V	PS2913-1-V-AX		50 pcs (Tape 50 pcs cut)	UL, BSI,	
PS2913-1-V-F3	PS2913-1-V-F3-		Embossed Tape 3 500	DIN EN 60747-5-5	
	AX		pcs/reel	approved	

Note: *1. When specifying CTR rank, please add "/CTR rank" after Order Number. ex. L rank : PS2913-1-AX/L

Note: *2. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit	
Diode	Forward Current	lF	50	mA	
	Forward Current Derating	⊿I⊧/°C	0.5	mA/°C	
	Peak Forward Current *1	IFP	0.5	А	
	Power Dissipation	PD	60	mW	
	Reverse Voltage	VR	6	V	
Detector	Collector to Emitter Voltage	V _{CEO}	120	V	
	Emitter to Collector Voltage	VECO	6	V	
	Collector Current	lc	30	mA	
	Power Dissipation Derating	⊿Pc/°C	1.2	mW/°C	
	Power Dissipation	Pc	120	mW	
Isolation Voltage *2		BV	2 500	Vr.m.s.	
Total Power Dissipation		Ρτ	160	mW	
Operating Ambient Temperature		TA	–55 to +100	°C	
Storage Temperature		T _{stg}	–55 to +150	°C	

Notes: *1. PW = 100 µs, Duty Cycle = 1 %

*2. AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input and output. Pins 1-2 shorted together, 3-4 shorted together.



ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	I _F = 1 mA	0.9	1.1	1.3	V
	Reverse Current	IR	V _R = 5 V			5	μA
	Terminal Capacitance	Ct	V = 0 V, f = 1 MHz		15		pF
Transistor	Collector to Emitter Dark Current	ICEO	I _F = 0 mA, V _{CE} = 120V			100	nA
Coupled	Current Transfer Ratio (Ic/I⊧) *1	CTR	I _F = 1 mA, V _{CE} = 5 V	50	100	200	%
	Collector Saturation Voltage	V _{CE(SAT)}	$I_F = 1 \text{ mA}, I_C = 0.2 \text{ mA}$		0.13	0.3	V
	Isolation Resistance	R _{I-0}	V _{I-O} = 1 kV _{DC}	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1 MHz		0.4		pF
	Rise Time *2	tr	V_{CC} = 5 V, I _C = 2 mA, R _L = 100 Ω		10		μs
	Fall Time ^{*2}	t _f			10		
	Turn-on Time *2	t _{on}	V_{CC} = 5 V, I _F = 1 mA, R _L = 5 k Ω		80		μs
	Storage Time *2	ts			5		
	Turn-off Time *2	t _{off}			50		

Notes: *1. CTR rank

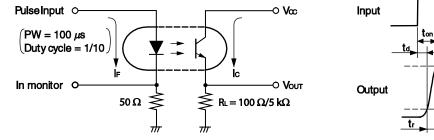
 N
 : 50 to 200 (%)

 K
 : 100 to 200 (%)

 L
 : 75 to 150 (%)

 M
 : 50 to 100 (%)

*2. Test circuit for switching time





<mark>_____toff</mark>

_tr

90%

10%



TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)

1.2 mW/°C

50

4

Collector to Emitter Voltage VCE(V)

2

6

0.6

0.4

0.2

Ambient Temperature TA (°C)

75

100

l⊧ = 5 mA

2mA

1 mA 0.5 mA

5 mA

2mA

1mA

I⊧ = 0.5 mA

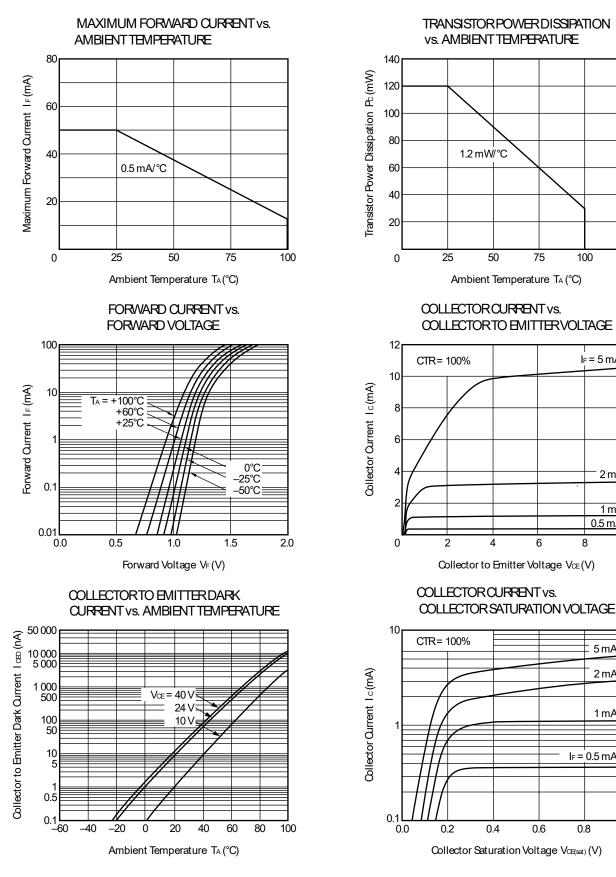
0.8

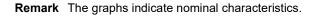
10

8

125

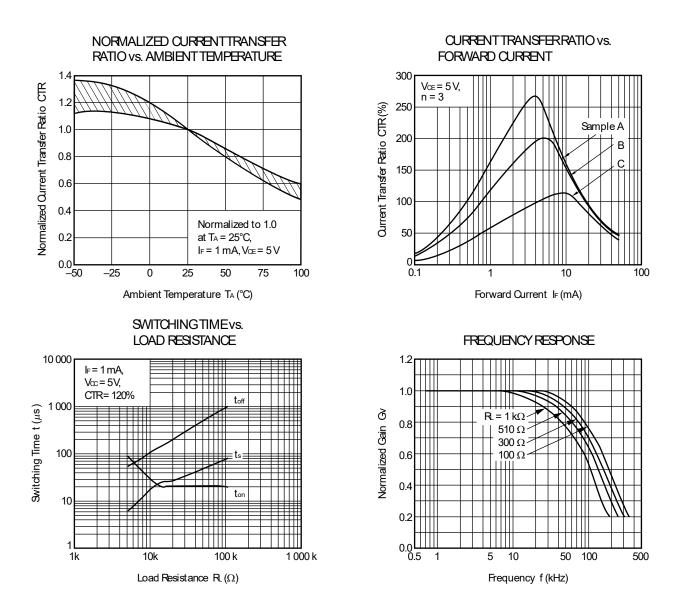
25







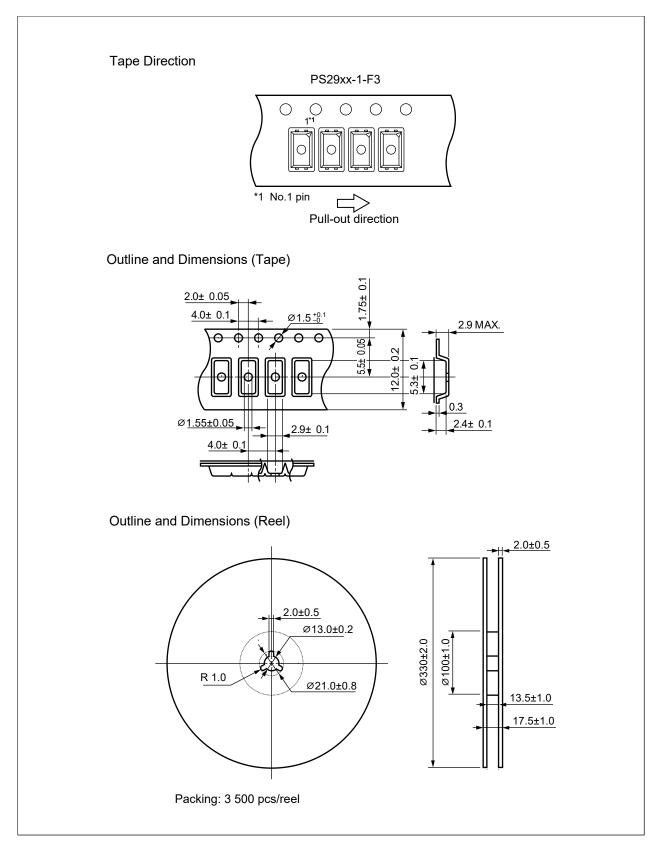
1.0



Remark The graphs indicate nominal characteristics.

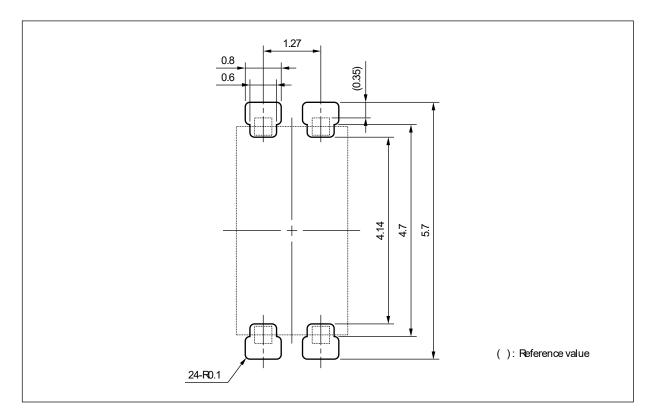


TAPING SPECIFICATIONS (UNIT: mm)





RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Remark This drawing is considered to meet air and outer creepage distance 4.0 mm minimum. All dimensions in this figure must be evaluated before use.



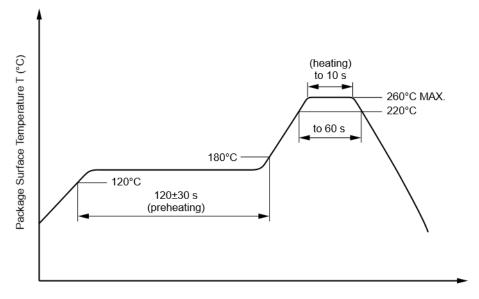
NOTES ON HANDLING

- 1. Recommended soldering conditions
 - (1) Infrared reflow soldering
 - Peak reflow temperature
 - Time of peak reflow temperature
 - Time of temperature higher than 220 °C
 - Time to preheat temperature from 120 to 180 °C 120 ± 30 s
 - Number of reflows
 - Flux

260 °C or below (package surface temperature) 10 seconds or less 60 seconds or less Three Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of

0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



- (2) Wave soldering
 - Temperature

Time (s)

- 260 °C or below (molten solder temperature)
- Time 10 seconds or less
- · Preheating conditions 120 °C or below (package surface temperature)
- Number of times One (Allowed to be dipped in solder including plastic mold portion.) • Flux
 - Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

- Peak Temperature (lead part temperature) 350 °C or below
- Time (each pins) 3 seconds or less
- Flux

Rosin flux containing small amount of chlorine

(The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

- (b) Please be sure that the temperature of the package would not be heated over 100 °C
- (4) Cautions
 - Flux Cleaning
 - Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.
 - Do not use fixing agents or coatings containing halogen-based substances.
- 2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.



 Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

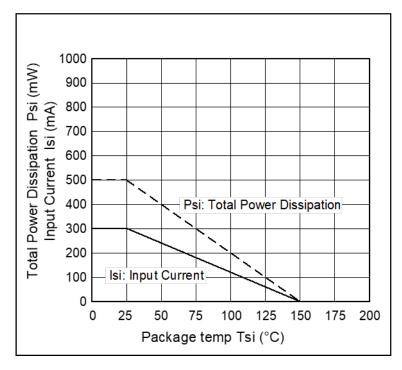
USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.
- 3. Avoid cleaning with Freon based or halogen-based (chlorinated etc.) solvents.
- 4. Do not use fixing agents or coatings containing halogen-based substances.

SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

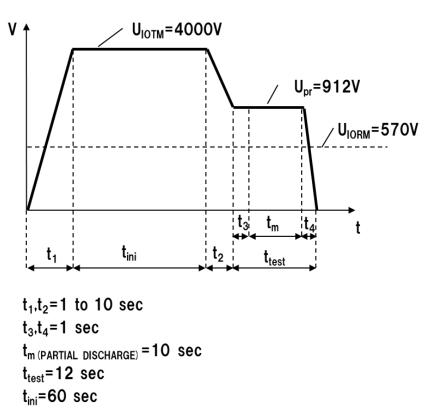
Parameter	Symbol	Rating	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		55/100/21	
Dielectric strength			
maximum operating isolation voltage	UIORM	570	V _{peak}
Test voltage (partial discharge test, procedure a for type test and	Upr	912	V _{peak}
random test)			
U_{pr} = 1.6 × U _{IORM} , P _d < 5 pC			
Test voltage (partial discharge test, procedure b for all devices)	Upr	1 068	V _{peak}
U_{pr} = 1.875 × U _{IORM} , P_d < 5 pC			
Highest permissible overvoltage	Utr	4 000	V _{peak}
Degree of pollution (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303-11))	CTI	175	
Material group (IEC 60664-1/DIN EN 60664-1 (VDE 0110-1))		III a	
Storage temperature range	T _{stg}	–55 to +150	°C
Operating temperature range	TA	–55 to +100	°C
Isolation resistance, minimum value			
V _{IO} = 500 V dc at T _A = 25 °C	Ris MIN.	10 ¹²	Ω
V _{IO} = 500 V dc at T _A MAX. at least 100 °C	Ris MIN.	10 ¹¹	Ω
Safety maximum ratings (maximum permissible in case of fault, see			
thermal derating curve)			
Package temperature	Tsi	150	°C
Current (input current I _F , Psi = 0)	lsi	300	mA
Power (output or total power dissipation)	Psi	500	mW
Isolation resistance			
V _{IO} = 500 V dc at T _A = Tsi	Ris MIN.	10 ⁹	Ω

Dependence of maximum safety ratings with package temperature

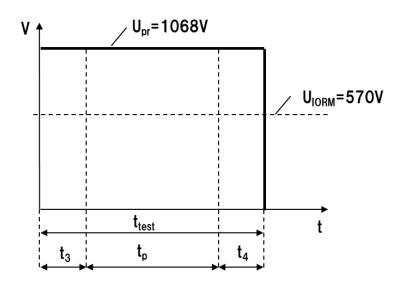












 $t_3, t_4 = 0.1$ sec $t_{p (PARTIAL DISCHARGE)} = 1.0$ sec $t_{test} = 1.2$ sec

Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
	• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
	 Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
	Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
	Do not burn, destroy, cut, crush, or chemically dissolve the product.
	• Do not lick the product or in any way allow it to enter the mouth.

All trademarks and registered trademarks are the property of their respective owners.



Notice

- 1. Descriptions of circuits, software and other related information in this document are provided only to illustrate the operation of semiconductor products and application examples. You are fully responsible for the incorporation or any other use of the circuits, software, and information in the design of your product or system. Renesas Electronics disclaims any and all liability for any losses and damages incurred by you or third parties arising from the use of these circuits, software, or information.
- Renesas Electronics hereby expressly disclaims any warranties against and liability for infringement or any other claims involving patents, copyrights, or other intellectual property rights of third parties, by or arising from the use of Renesas Electronics products or technical information described in this document, including but not limited to, the product data, drawings, charts, programs, algorithms, and application examples.
- 3. No license, express, implied or otherwise, is granted hereby under any patents, copyrights or other intellectual property rights of Renesas Electronics or others.
- 4. You shall be responsible for determining what licenses are required from any third parties, and obtaining such licenses for the lawful import, export, manufacture, sales, utilization, distribution or other disposal of any products incorporating Renesas Electronics products, if required.
- 5. You shall not alter, modify, copy, or reverse engineer any Renesas Electronics product, whether in whole or in part. Renesas Electronics disclaims any and all liability for any losses or damages incurred by you or third parties arising from such alteration, modification, copying or reverse engineering.
- Renesas Electronics products are classified according to the following two quality grades: "Standard" and "High Quality". The intended applications for each Renesas Electronics product depends on the product's quality grade, as indicated below.

"Standard": Computers; office equipment; communications equipment; test and measurement equipment; audio and visual equipment; home electronic appliances; machine tools; personal electronic equipment; industrial robots; etc.

"High Quality": Transportation equipment (automobiles, trains, ships, etc.); traffic control (traffic lights); large-scale communication equipment; key financial terminal systems; safety control equipment; etc.

Unless expressly designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not intended or authorized for use in products or systems that may pose a direct threat to human life or bodily injury (artificial life support devices or systems; surgical implantations; etc.), or may cause serious property damage (space system; undersea repeaters; nuclear power control systems; aircraft control systems; key plant systems; military equipment; etc.). Renesas Electronics disclaims any and all liability for any damages or losses incurred by you or any third parties arising from the use of any Renesas Electronics product that is inconsistent with any Renesas Electronics data sheet, user's manual or other Renesas Electronics document.

- 7. No semiconductor product is absolutely secure. Notwithstanding any security measures or features that may be implemented in Renesas Electronics hardware or software products, Renesas Electronics shall have absolutely no liability arising out of any vulnerability or security breach, including but not limited to any unauthorized access to or use of a Renesas Electronics product or a system that uses a Renesas Electronics product. RENESAS ELECTRONICS DOES NOT WARRANT OR GUARANTEE THAT RENESAS ELECTRONICS PRODUCTS, OR ANY SYSTEMS CREATED USING RENESAS ELECTRONICS PRODUCTS WILL BE INVULNERABLE OR FREE FROM CORRUPTION, ATTACK, VIRUSES, INTERFERENCE, HACKING, DATA LOSS OR THEFT, OR OTHER SECURITY INTRUSION ("Vulnerability Issues"). RENESAS ELECTRONICS DISCLAIMS ANY AND ALL RESPONSIBILITY OR LIABILITY ARISING FROM OR RELATED TO ANY VULNERABILITY ISSUES. FURTHERMORE, TO THE EXTENT PERMITTED BY APPLICABLE LAW, RENESAS ELECTRONICS DISCLAIMS ANY AND ALL WARRANTIES, EXPRESS OR IMPLIED, WITH RESPECT TO THIS DOCUMENT AND ANY RELATED OR ACCOMPANYING SOFTWARE OR HARDWARE, INCLUDING BUT NOT LIMITED TO THE IMPLIED WARRANTIES OF MERCHANTABILITY, OR FITNESS FOR A PARTICULAR PURPOSE.
- 8. When using Renesas Electronics products, refer to the latest product information (data sheets, user's manuals, application notes, "General Notes for Handling and Using Semiconductor Devices" in the reliability handbook, etc.), and ensure that usage conditions are within the ranges specified by Renesas Electronics with respect to maximum ratings, operating power supply voltage range, heat dissipation characteristics, installation, etc. Renesas Electronics disclaims any and all liability for any malfunctions, failure or accident arising out of the use of Renesas Electronics products outside of such specified ranges.
- 9. Although Renesas Electronics endeavors to improve the quality and reliability of Renesas Electronics products, semiconductor products have specific characteristics, such as the occurrence of failure at a certain rate and malfunctions under certain use conditions. Unless designated as a high reliability product or a product for harsh environments in a Renesas Electronics data sheet or other Renesas Electronics document, Renesas Electronics products are not subject to radiation resistance design. You are responsible for implementing safety measures to guard against the possibility of bodily injury, injury or damage caused by fire, and/or danger to the public in the event of a failure or malfunction of Renesas Electronics products, such as safety design for hardware and software, including but not limited to redundancy, fire control and malfunction prevention, appropriate treatment for aging degradation or any other appropriate measures. Because the evaluation of microcomputer software alone is very difficult and impractical, you are responsible for evaluating the safety of the final products or systems manufactured by you.
- 10. Please contact a Renesas Electronics sales office for details as to environmental matters such as the environmental compatibility of each Renesas Electronics product. You are responsible for carefully and sufficiently investigating applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive, and using Renesas Electronics products in compliance with all these applicable laws and regulations. Renesas Electronics disclaims any and all liability for damages or losses occurring as a result of your noncompliance with applicable laws and regulations.
- 11. Renesas Electronics products and technologies shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable domestic or foreign laws or regulations. You shall comply with any applicable export control laws and regulations promulgated and administered by the governments of any countries asserting jurisdiction over the parties or transactions.
- 12. It is the responsibility of the buyer or distributor of Renesas Electronics products, or any other party who distributes, disposes of, or otherwise sells or transfers the product to a third party, to notify such third party in advance of the contents and conditions set forth in this document.
- This document shall not be reprinted, reproduced or duplicated in any form, in whole or in part, without prior written consent of Renesas Electronics.
 Please contact a Renesas Electronics sales office if you have any questions regarding the information contained in this document or Renesas Electronics products.
- (Note1) "Renesas Electronics" as used in this document means Renesas Electronics Corporation and also includes its directly or indirectly controlled subsidiaries.
- (Note2) "Renesas Electronics product(s)" means any product developed or manufactured by or for Renesas Electronics.

(Rev.5.0-1 October 2020)

Corporate Headquarters

TOYOSU FORESIA, 3-2-24 Toyosu, Koto-ku, Tokyo 135-0061, Japan

www.renesas.com

Trademarks

Renesas and the Renesas logo are trademarks of Renesas Electronics Corporation. All trademarks and registered trademarks are the property of their respective owners.

Contact information

For further information on a product, technology, the most up-to-date version of a document, or your nearest sales office, please visit: <u>www.renesas.com/contact/</u>.